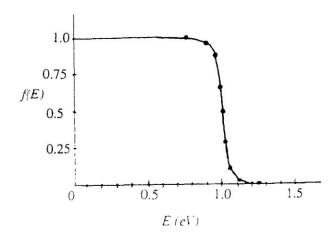
Chapter 3 Homework

<u>Prob. 3.2</u> Plot Fermi function for $E_F = 1 \text{ eV}$.

$$f(E) = [1 + e^{(E - E_F)/kT}]^{-1}$$

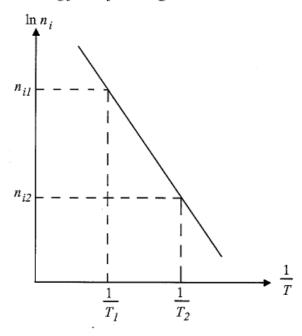
We will choose E in eV and therefore use kT = 0.0259

E(eV)	$(E-E_F)/kT$	<i>f</i> (<i>E</i>)
0.75	-9.6525	0.99994
0.90	-3.8610	0.97939
0.95	-1.9305	0.87330
0.98	-0.7722	0.68399
1.02	+0.7722	0.31600
1.05	+1.9305	0.12669
1.10	+3.8610	0.02061
1.25	+9.6525	0.00006



Prob. 3.6

Find Eg for Si from Figure 3-17.



for n_{i1} and n_{i2} on graph

$$n_{i1} = 3 \cdot 10^{14} \quad \frac{1}{T_i} = 2 \cdot 10^{-3} \, \frac{_1}{_K}$$

$$n_{i2} = 10^8$$
 $\frac{1}{T_2} = 4 \cdot 10^{-3} \frac{1}{K}$

This result is approximate because the temperature dependences of $N_{_{\rm C}},\,N_{_{\rm V}},$ and $E_{_{\rm g}}$ are neglected.

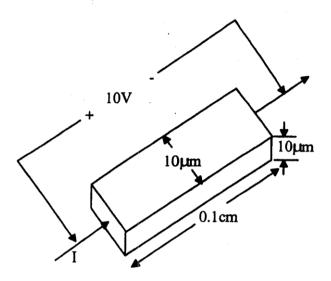
$$\begin{split} n_{i} &= \sqrt{N_{C}N_{V}} \cdot e^{-\frac{E_{g}}{2kT}} \ \, \rightarrow \ \, E_{g} = -2kT \cdot ln \frac{n_{i}}{\sqrt{N_{C}N_{V}}} \ \, \rightarrow \ \, ln \, n_{i} = -\frac{E_{g}}{2kT} + ln \sqrt{N_{C}N_{V}} \\ ln \, \frac{n_{i1}}{n_{i2}} &= ln \, n_{i1} - ln \, n_{i2} = \left(-\frac{E_{g}}{2kT_{1}} + ln \sqrt{N_{C}N_{V}} \right) - \left(-\frac{E_{g}}{2kT_{2}} + ln \sqrt{N_{C}N_{V}} \right) = \frac{E_{g}}{2k} \cdot \left(\frac{1}{T_{2}} - \frac{1}{T_{1}} \right) \\ for \, Si \, (see \, above) \, \rightarrow \ \, E_{g} = 2k \cdot \left(\frac{ln \, \frac{n_{i1}}{n_{i2}}}{\frac{1}{T_{2}} - \frac{1}{T_{1}}} \right) = 2 \cdot 8.62 \cdot 10^{14} \cdot \left(\frac{ln \, \frac{3 \cdot 10^{14}}{10^{8}}}{4 \cdot 10^{-3} \frac{1}{K} - 2 \cdot 10^{-3} \frac{1}{K}} \right) = 1.3 eV \end{split}$$

Prob. 3.10

At t = 400K, Figure 3-17 indicates that n>>n_i for Si doped with Nd= 10^{15} cm⁻³; so, the Si would be n-type. At T = 400K, Figure 3-17 indicates that n ~ n_i ~ 10^{15} cm⁻³ for Ge doped with N_d = 10^{15} cm⁻³; so, the Ge would require more donors for useful n-type doping.

Prob. 3.13 (FROM 5th EDITION, see 6th edition answers following)

(a) A Si bar 0.1 cm long and 100 μm² in cross sectional area is doped with 10¹⁷ cm⁻³ antimony. Find the current at 300K with 10V applied.



From Fig.3-23, $\mu_n = 700 \text{ cm}^2/\text{V-s}$

$$\sigma = q\mu_n n_0 = 1.6 \times 10^{-19} \times 700 \times 10^{17} = 11.2 \,(\Omega \cdot \text{cm})^{-1} = \rho^{-1}$$

$$\rho = 0.0893 \,\Omega \cdot \text{cm}$$

$$R = \rho L/A = 0.0893 \times 0.1/10^{-6} = 8.93 \times 10^3 \,\Omega$$

$$I = V/R = 10/(8.93 \times 10^3) = 1.12 \,\text{mA}$$

Prob. 3-13, 6th Edition Answers are:

a. $0.16 \text{ A} (10 \text{V}/10^{-4} \text{cm} \rightarrow \text{velocity saturation, making} \text{V}_s = 10^7 \text{ cm/s from Fig. 3-24.}, \text{ and then } I = q*A*n*V_s)$ b. low field 0.74 ns, high field 10 ps.